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Company Internal Address:
0
Street Address:
No. 8, Li-Hsin Rd. 6 Science-Based Industrial Park Hsin-Chu, Taiwan 300-77
Taiwan, R.O.C.
Additional name & address attached? Yes X No
58317
ion, the execution date of the application is: 12/19/03  B. Patent No.(s)
D. 1 store (10.15)
ed? Yes X No
6. Total no. of applications and patents involved:: 1
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do hereby sell, assign and transfer to					
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in and to any and all improvements which a	in and to any and all improvements which are disclosed in the invention entitled:				
High Temperature Hydrogen Annealing Of A Gate Insulator Layer To Increase Etching Selectivity Between Conductive Gate Structure And Gate Insulator Layer					

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in and to any and all improvements which are disclosed in the invention entitled:					
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and which is found in					
(a) X U.S. patent application executed on	Aven date herewith				
(b) U.S. patent application executed on					

(c)		U.S. application serial no.	filed on	
(d)		U,Ş, patent no.	issued	
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(e)	X	and any legal equivalent thereof in a foreign	country, including the right to dam priority	
	inuati	•	said invention by the above application or any disasto letters patent any re-lasue or re-examination	
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may or pi any appi	nent be k rocee and a icatio	facts and documents relating to said invention nown and accessible to ASSIGNOR and will the ding related thereto and will promptly execute a all papers, instruments or affidavits required to	ill, upon its request, be provided promptly with all and said Letters Patent and legal equivalents as eastify as to the same in any interference, litigation and deliver to ASSIGNEE or its legal representatives apply for, obtain, maintain, issue and enforce said said equivalents thereof which may be necessary	
V, Pri		ESS WHEREOF, I / We have signed this 2 / (9 / 0 3 (Date of		
WA		C Date of algoing must be the same as the date of execution of the date of executions.		
			Signature of Assignories, Chia-Lin Chen Clichun Chen	
If ASSIGNOR is a legal entity complete the following information				
			Type or print the name of the above person authorized to sign on behalf of ASSIGNOR	
			Title	
	Note. 261).	No witnessing, notarization or legalization is necessary, if the assignment of the next page if notarization is desired.	nent is notarized or legalized then it will only be prima facia evidence (35 USC	
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and which is found in					
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(b) U.S. patent application executed on					
	filed on				
(d) U.S. patent no.	beuzai				
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	Shith Chang Chen Signature of ASSICHOR(8) Chien How Chen				
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